NSN 5961-01-082-8808

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-082-8808 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 regulator voltage **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 7.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release 5009 professional/industrial association standard Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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